## NSN 5961-00-524-0175

**Fiig:** A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-524-0175 **Inclosure Material:** Ceramic or plastic **Overall Length:** 0.780 inches **Terminal Length:** 0.100 inches **Overall Height:** 0.020 inches **Overall Width:** 0.190 inches **Response Time:** 45.0 nanoseconds all transistor **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -60.0 collector to base voltage, dc all transistor and -40.0 collector to emitter voltage, dc all transistor and -5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** -0.60 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 300.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: pnp **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No